

Threshold Detector 10 to 2000 MHz

Technical Data

UTD-2004

Features

- **Frequency Range: 10 to 2000 MHz**
- **Sensitive Threshold: -25dBm**
- **Threshold Externally Programmable with One Resistor**
- **Wide Threshold Range: -25 to -10 dBm**
- **TTL Output**
- **Temperature Compensated Threshold**
- **2.5 mA (Typ) Power Consumption @ +5 VDC**

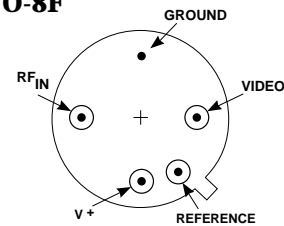
Applications

- **Specifically Designed for System Built-in Test**
- **Built for Retrofitting**
- **Channel RF Activity Monitoring**

Description

The UTD-2004 is a sensitive microwave threshold detector which provides efficient and accurate RF level measurement at critical system points. It contains a planar tunnel diode detector, precision integrated circuit operational amp, comparator, and a temperature compensated voltage reference assembly. The unit is built with chip and wire construction on a thin-film substrate for small size and ruggedness.

Pin Configuration TO-8F



Maximum Ratings

| Parameter | Maximum |
|--------------------------------|-----------------|
| DC Voltage | +20 V |
| Continuous RF Input Power | +10 dBm |
| "R" Series Burn-In Temperature | +100°C |
| Operating Case Temperature | -55°C to +100°C |
| Storage Temperature | -55°C to +100°C |

Weight: (typical) 2.1 grams

Electrical Specifications

(Measured in 50 Ω system @ +5 VDC)

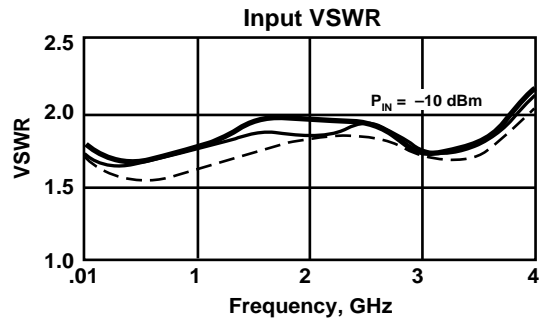
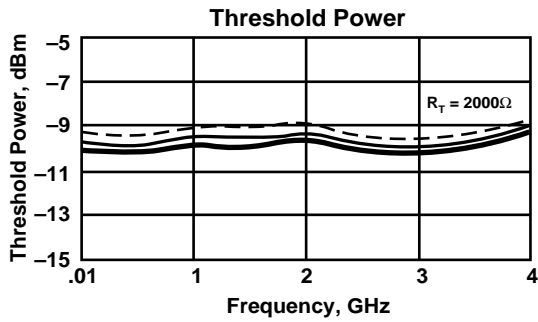
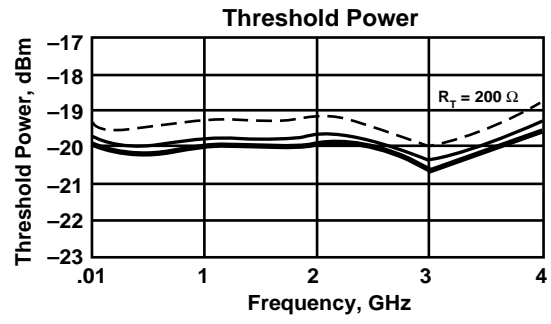
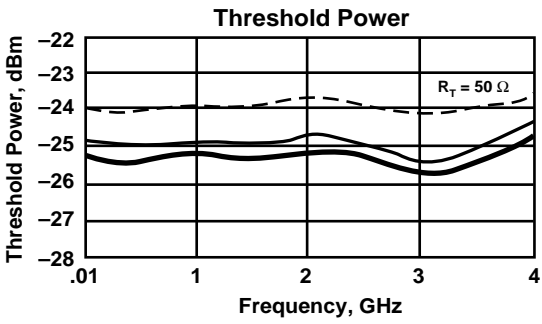
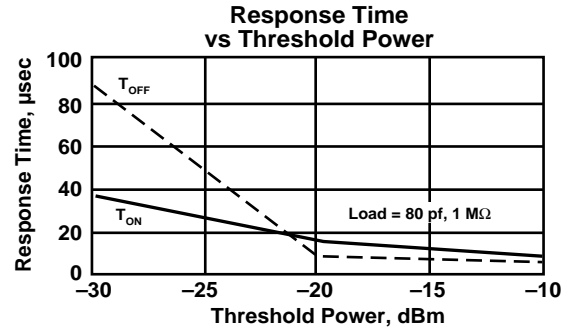
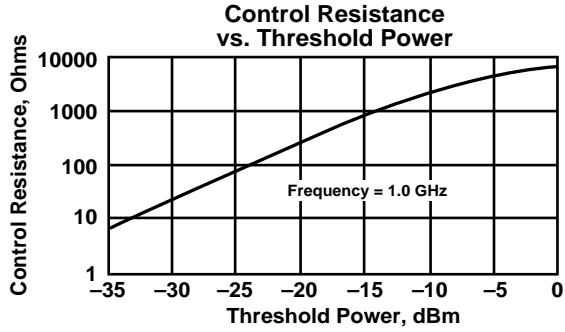
| Symbol | Characteristic | Typical $T_c = 25^\circ\text{C}$ | Guaranteed Specifications | | Unit |
|--------|--|-------------------------------------|---------------------------------|------------------------------------|---------------|
| | | | $T_c = 0$ to 50°C | $T_c = -55$ to $+85^\circ\text{C}$ | |
| — | Frequency (Min.) | 10-2000 | 10-2000 | 100-2000 | MHz |
| — | Input Operating Range | -25 to -10 | -25 to -10 | -25 to -10 | dBm |
| — | Input Flatness (Max.) | ± 0.5 | ± 1.0 | ± 1.0 | dB |
| — | Input VSWR (Max.) | | | | |
| — | -25 < P_{IN} < -20 dBm | 1.5:1 | 2.0:1 | 2.0:1 | — |
| — | -20 < P_{IN} < -10 dBm | 1.8:1 | 2.2:1 | 2.2:1 | — |
| — | Threshold Temperature Stability (Max.) | — | — | ± 1.5 | dB |
| — | Threshold Hysteresis (Max.) | 0.7 | 1.5 | 1.5 | dB |
| — | Response Time (see Note 1) (Max.) | | | | |
| — | T_{ON} , 90% RF to TTL "1" | 20 | 300 | 300 | μs |
| — | T_{OFF} , 10% RF to TTL "0" | 30 | 300 | 300 | μs |
| — | Control Resistance at Threshold Level: | | | | |
| — | $P_{IN} = -25$ dBm | 50 | — | — | Ω |
| — | $P_{IN} = -20$ dBm | 200 | — | — | Ω |
| — | $P_{IN} = -10$ dBm | 2000 | — | — | Ω |
| — | Output Compatibility (Standard TTL Loads) (Min.) | 2 | 1 | 1 | — |
| — | Output Voltage (see Note 2) (Min.) | 3.6 | 2.7 | 2.7 | V |
| — | Supply Voltage | 5-20 | 5 | 5 | V |
| — | Supply Current @ +5 VDC (Max.) | 2.5 | 5.0 | 5.0 | mA |

Notes: 1. Response time for input change > 3 dB above CW threshold. $R_{LOAD} = 1$ M Ω , $C_{LOAD} = 80$ pF.

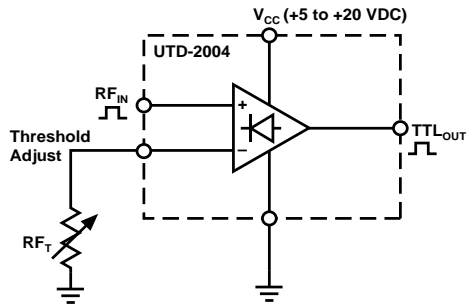
2. Output voltage for $P_{IN} = >$ threshold, $R_{LOAD} = 1$ M Ω .

Typical Performance Over Temperature (@ +5 VDC unless otherwise noted)

Key: +25°C ———
 +85°C - - - -
 -55°C ———



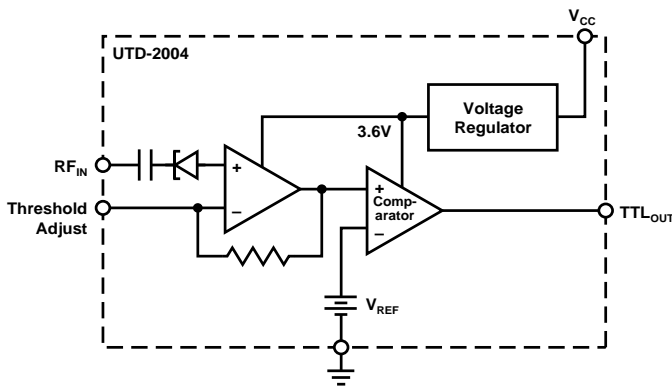
Threshold Adjust



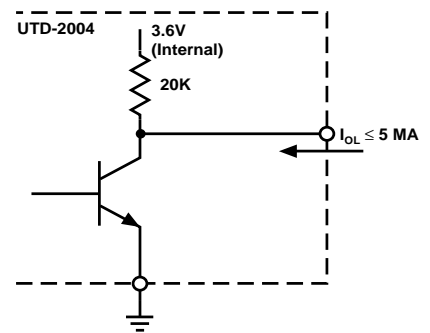
Threshold Adjust at +15 VDC Bias

| R_T, Ω | Sensitivity dBm, (typ) |
|---------------|------------------------|
| 50 | -25 |
| 200 | -20 |
| 2000 | -10 |

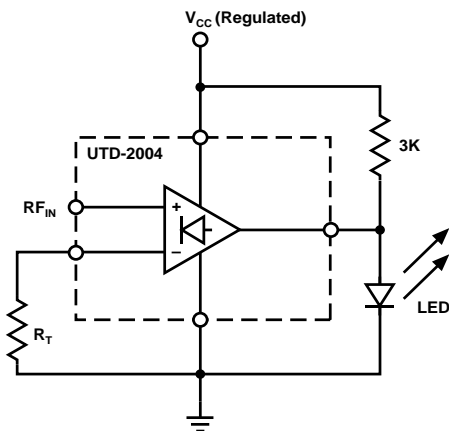
Simplified Schematic



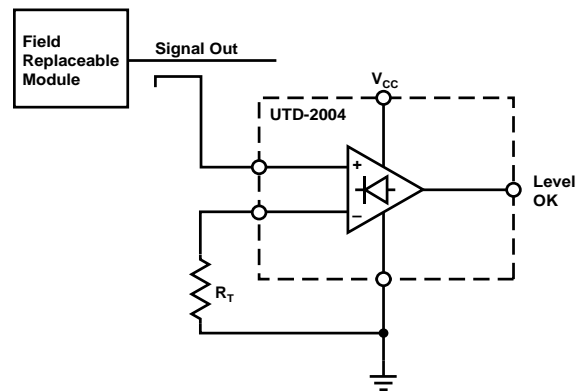
Output Schematic



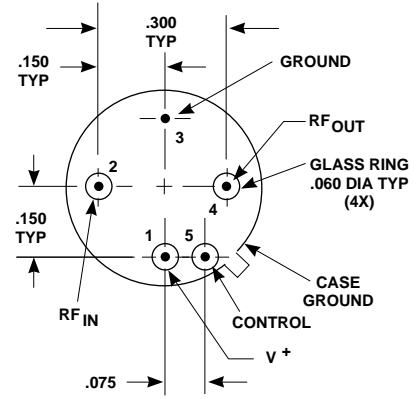
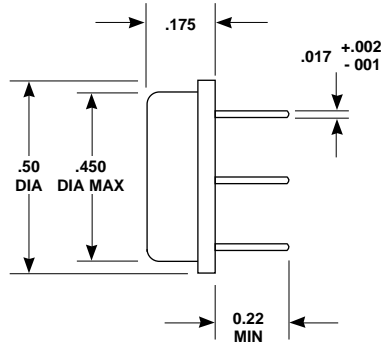
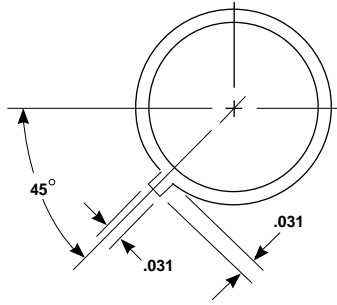
Indicator Drive Circuit



Built-In Test Detector



**Case Drawings
TO-8F**



APPROXIMATE WEIGHT 2.1 GRAMS

- NOTES (UNLESS OTHERWISE SPECIFIED):**
 1. DIMENSIONS ARE SPECIFIED IN INCHES
 2. TOLERANCES: xx ± .02
 xxx ± .010

H

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